

PAAVAI ENGINEERING COLLEGE, NAMAKKAL – 637 018
(AUTONOMOUS)
M.E. VLSI DESIGN
REGULATIONS 2015
CURRICULUM

SEMESTER I

Course Code	Course Title	L	T	P	C
PMA15103	Applied Mathematics for Electronics Engineers	3	2	0	4
PVL15102	Digital Signal Processing Integrated Circuits	3	2	0	4
PVL15103	Advanced Digital System Design	3	2	0	4
PVL15104	VLSI Design Techniques	3	2	0	4
PVL15105	Solid State Device Modeling and Simulation	3	2	0	4
E I	Elective I	3	0	0	3
PVL15107	VLSI Design Lab I	0	0	4	2

SEMESTER II

Course Code	Course Title	L	T	P	C
PVL15201	Analysis and Design of Analog Integrated Circuits	3	2	0	4
PVL15202	Computer Aided Design of VLSI Circuits	3	2	0	4
PVL15203	VLSI Signal Processing	3	2	0	4
E II	Elective II	3	0	0	3
E III	Elective III	3	0	0	3
E IV	Elective IV	3	0	0	3
PVL15204	VLSI Design Lab II	0	0	4	2

LIST OF ELECTIVES FOR II SEMESTER

ELECTIVE I

Course Code	Course Title	L	T	P	C
PVL15151	Low Power VLSI Design	3	0	0	3
PVL15152	ASIC Design	3	0	0	3
PVL15153	Hardware Design Verification Techniques	3	0	0	3
PVL15154	Communication Networks	3	0	0	3

ELECTIVE II

Course Code	Course Title	L	T	P	C
PVL15251	CMOS VLSI Design	3	0	0	3
PVL15252	Design of Semiconductor Memories	3	0	0	3
PVL15253	VLSI Technology	3	0	0	3
PVL15254	Advanced Microprocessors and Microcontrollers	3	0	0	3

ELECTIVE III

Course Code	Course Title	L	T	P	C
PVL15351	Analog VLSI Design	3	0	0	3
PVL15352	Physical Design of VLSI Circuits	3	0	0	3
PVL15353	Neural Networks and Applications	3	0	0	3
PVL15354	Three Dimensional Network on chip	3	0	0	3

ELECTIVE IV

Course Code	Course Title	L	T	P	C
PVL15451	Nano Electronics	3	0	0	3
PVL15452	Reliability Engineering	3	0	0	3
PVL15453	Electromagnetic Interference and Compatibility in System Design	3	0	0	3
PVL15454	VLSI For Wireless Communication	3	0	0	3

PMA15103 APPLIED MATHEMATICS FOR ELECTRONICS ENGINEERS 3 2 0 4

OBJECTIVES:

- To gain fundamental knowledge of fuzzy sets, fuzzy logic, fuzzy decision making and fuzzy control systems.
- To focus on the concept of random variables and distributions.
- To understand the concepts of matrix theory
- To know about dynamic programming and its applications.
- To understand and compute quantitative metrics of performance for queuing systems.

UNIT I FUZZY LOGIC 9+6

Classical logic – Multivalued logics – Fuzzy propositions – Fuzzy quantifiers

UNIT II MATRIX THEORY 9+6

Generalized Eigen values and Eigen vectors - Some important matrix factorizations – The Cholesky decomposition – QR factorization – Least squares method – Singular value decomposition - Toeplitz matrices and some applications

UNIT III ONE DIMENSIONAL RANDOM VARIABLES 9+6

Random variables - Probability function – moments – moment generating functions and their properties – Binomial, Poisson, Geometric, Uniform, Exponential, Gamma and Normal distributions

UNIT IV DYNAMIC PROGRAMMING 9+6

Dynamic programming – Principle of optimality – Forward and backward recursion – Applications of dynamic programming – Problem of dimensionality

UNIT V QUEUING MODELS 9+6

Markovian queues – Single and Multi-server Models – Little’s formula -Machine Interference Model – Steady State analysis – Self Service queue.

TOTAL: 45+30 PERIODS

OUTCOMES:

After Completion of the course, the students will be able to:

- Understand the basic principles of fuzzy logic.
- Learn the basics and gained the skill for specialized studies and research.

- Develop efficient algorithms for solving dynamic programming problems, to acquire skills in handling situation involving random variable.
- Know the basic characteristic features of a queuing system and acquire skills in analyzing queuing models.

REFERENCES

1. George J. Klir and Yuan, B., “Fuzzy sets and fuzzy logic, Theory and applications,” Prentice Hall of India Pvt. Ltd., 1997.
2. Moon, T.K., Sterling, W.C., “Mathematical methods and algorithms for signal processing”, Pearson Education, 2000.
3. Richard Johnson, Miller & Freund’s, “Probability and Statistics for Engineers”, 7th Edition, Prentice Hall of India, Private Ltd., New Delhi (2007).
4. Taha, H.A., “Operations Research, An introduction”, 7th edition, Pearson education editions, Asia, New Delhi, 2002.
5. Donald Gross and Carl M. Harris, “Fundamentals of Queuing theory”, 2nd edition, John Wiley and Sons, New York (1985).

WEB LINKS

1. <http://nptel.ac.in/courses/111108066/>
2. <http://nptel.ac.in/courses/111104079/>
3. <https://www.youtube.com/watch?v=xGkpXk-AnWU>

PVL15102 DIGITAL SIGNAL PROCESSING INTEGRATED CIRCUITS 3 2 0 4

OBJECTIVES:

- To familiarize the Number systems concept and Arithmetic Units.
- To understand the concepts of Digital signal processing.
- To study the concepts & gain knowledge about digital filters.
- To know the DSP architectures.
- To understand the Design of integrated circuit design.

UNIT I NUMBER SYSTEMS AND ARITHMETIC UNITS 9+6

Conventional Number system, Redundant Number system, Residue Number System, Bit Parallel and Bit Serial Arithmetic, Distributed arithmetic, Basic Shift Accumulator, Reducing the memory size, Complex multipliers, improved shift-Accumulator.

UNIT II DIGITAL SIGNAL PROCESSING 9+6

Digital signal processing, Sampling of analog signals, Selection of sample frequency, Signal-processing systems, Frequency response, Transfer functions, Signal flow graphs, Filter structures, Adaptive DSP algorithms, DFT-The Discrete Fourier Transform, FFT-The Fast Fourier Transform Algorithm, Image coding, Discrete cosine transforms.

UNIT III DIGITAL FILTERS AND FINITE WORD LENGTH EFFECTS 9+6

FIR filters, FIR filter structures, FIR chips, IIR filters, Specifications of IIR filters, Mapping of analog transfer functions, Mapping of analog filter structures, multirate systems, Interpolation with an integer factor L, Sampling rate change with a ratio L/M, multirate filters. Finite word length effects -Parasitic oscillations, Scaling of signal levels, Round-off noise, measuring round-off noise, Coefficient sensitivity, Sensitivity and noise

UNIT IV DSP INTEGRATED CIRCUITS AND VLSI CIRCUIT TECHNOLOGIES 9+6

Standard digital signal processors, Application specific IC's for DSP, DSP systems, DSP system design, Integrated Circuits design. MOS transistors, MOS Logic, VLSI Process technologies Trends in CMOS technologies

UNIT V DSP ARCHITECTURES AND SYNTHESIS OF DSP ARCHITECTURES 9+6

DSP system architectures, Standard DSP architecture, Ideal DSP architectures, Multiprocessors and multi-computers, Systolic and Wave front arrays, Shared memory architectures - Mapping of DSP

algorithms onto hardware, Implementation based on complex PEs, Shared memory architecture with Bit – serial PEs.

TOTAL: 45+30 PERIODS

OUTCOMES:

After Completion of the course, the students will be able to:

- Learn the basics of DSP processors.
- Learn the concepts of digital signal processing.
- Design different digital filters.
- Understand DSP architectures.
- Design the digital integrated circuits.

REFERENCES

1. Lars Wanhammer, “DSP Integrated Circuits”, Academic press, New York 1999.
2. A.V.Oppenheim et.al, “Discrete-time Signal Processing” Pearson education, 2000.
3. Emmanuel C. Ifeachor, Barrie W. Jervis, “Digital signal processing – Apractical approach”, Second edition, Pearson education, Asia 2001.
4. Keshab K.Parhi, “VLSI digital Signal Processing Systems design and Implementation” John Wiley& Sons, 1999.
5. Bayoumi & Magdy A., “VLSI Design Methodologies for Digital Signal Processing Architectures”, BSPublications, 2005.

WEB LINKS

1. <http://nptel.ac.in/courses/117105075/>
2. <http://nptel.ac.in/courses/117101001/>
3. https://www.youtube.com/watch?v=_hKArr0D8M8

OBJECTIVES:

- To familiarize the practical issues of sequential circuit design
- To understand the concepts of Asynchronous Sequential Circuit Design.
- To study the concepts & gain knowledge about different fault diagnosis and testing methods.
- To know the concepts of programmable Devices.

UNIT I SEQUENTIAL CIRCUIT DESIGN**9+6**

Analysis of Clocked Synchronous Sequential Networks (CSSN) - Modeling of CSSN –State Assignment and Reduction – Design of CSSN – Design of Iterative Circuits– ASM Chart – ASM Realization, Design of Arithmetic circuits for Fast adder- Array Multiplier

UNIT II ASYNCHRONOUS SEQUENTIAL CIRCUIT DESIGN**9+6**

Analysis of Asynchronous Sequential Circuit (ASC) – Flow Table Reduction – Races in ASC – State Assignment Problem and the Transition Table – Design of ASC – Static and Dynamic Hazards – Essential Hazards – Design of Hazard free circuits - Data Synchronizers –Designing Vending Machine Controller – Mixed Operating Mode Asynchronous Circuits. Practical issues such as clock skew, synchronous and asynchronous inputs and switch bouncing

UNIT III FAULT DIAGNOSIS & TESTING**9+6**

Fault diagnosis: Fault Table Method – Path Sensitization Method – Boolean Difference Method –Kohavi Algorithm – Tolerance Techniques – The Compact Algorithm. Design for testability: Test Generation – Masking Cycle – DFT Schemes. Circuit testing fault model, specific and random faults, testing of sequential circuits, Built in Self Test, Built in Logic Block observer (BILBO), signature analysis.

UNIT IV SYNCHRONOUS DESIGN USING PROGRAMMABLE DEVICES**9+6**

EPLD to Realize a Sequential Circuit – Programmable Logic Devices – Designing a Synchronous Sequential Circuit using a GAL – EPROM – Realization State machine using PLD – FPGA – Xilinx FPGA– Xilinx 2000 -Xilinx 3000

UNIT V SYSTEM DESIGN USING VHDL**9+6**

Design flow - VHDL Code Structure – Library, Entity, Architecture - Behavioural, Data flow and Structural modelling - Data Types - Operators and Attributes – Signals and Variables - Concurrent and

Sequential Code – Packages and Components – Subprograms: Functions and Procedures – Design Examples - Test Benches.

TOTAL: 45 +30 PERIODS

OUTCOMES:

After Completion of the course, the students will be able to:

- Learn the synchronous sequential circuit design
- Learn the design of Asynchronous sequential circuit design
- Know about Fault Diagnosis& Testing Methods
- Study the programmable logic devices
- Carry out the system design using VHDL

REFERENCES

1. Charles H.RothJr “Fundamentals of Logic Design”, Thomson Learning 2004.
2. Parag K.Lala “An introduction to Logic Circuit Testing” Morgan and clay pool publishers, 2009.
3. J.F.Wakerly, “Digital Design principles and practices”, PHI publications, 2005.
4. Mark Zwolinski, “Digital System Design with VHDL” Pearson Education, 2004.
5. H.Charles Roth, “Fundamentals of Logic design”, Thomson Learning, 2003.

WEB LINKS

1. <http://nptel.ac.in/courses/117106086/>
2. <http://nptel.ac.in/courses/117108040/>
3. <http://nptel.ac.in/courses/117105080/>

PVL15104 VLSI DESIGN TECHNIQUES 3 2 0 4

OBJECTIVES:

- To study the basics of MOS transistor and IC fabrication.
- To learn inverters characteristics and logic function.
- To understand circuit characterization and performance estimation.
- To study VLSI circuits.
- To learn Verilog HDL and design VLSI circuits.

UNIT I VLSI DESIGN PROCESS AND MOS TRANSISTOR THEORY 9+6

VLSI Design Process – Architectural Design – Logical Design – Physical Design – Layout Styles – Full custom, Semicustom approaches. MOS transistors, CMOS logic, MOS transistor theory – Introduction, Enhancement mode transistor action, Ideal I-V characteristics, Simple MOS capacitance Models, Detailed MOS gate capacitance model, Detailed MOS Diffusion capacitance model, Non ideal I-V effects, DC transfer characteristics, VLSI Design flow.

UNIT II INVERTERS AND LOGIC GATES 9+6

NMOS and CMOS Inverters, Stick diagram, Inverter ratio, DC and transient characteristics , switching times, Super buffers, Driving large capacitance loads, CMOS logic structures , Transmission gates, Static CMOS design, dynamic CMOS design.

UNIT III CIRCUIT CHARACTERIZATION AND PERFORMANCE ESTIMATION 9+6

Resistance estimation, Capacitance estimation, Inductance, switching characteristics, transistor sizing, power dissipation and design margining, Charge sharing, Scaling

UNIT IV VLSI SYSTEM COMPONENTS CIRCUITS 9+6

Multiplexers, Decoders, comparators, priority encoders, Shift registers Arithmetic circuits – Ripple carry adders, Carry look ahead adders, High-speed adders, Multipliers.

UNIT V VERILOG HARDWARE LANGUAGE 9+6

Overview of digital design with Verilog HDL, hierarchical modeling concepts, modules and port definitions, gate level modeling, data flow modeling, behavioral modeling, task & functions, Test Bench.

TOTAL: 45+30 PERIODS

OUTCOMES:

After Completion of the course, the students will be able to:

- Understand basics of MOS transistor and IC fabrication.
- Know inverters characteristics and logic function.
- Learn circuit characterization and performance estimation.
- Analyze the concepts of VLSI circuits.
- Understand Verilog HDL and design VLSI circuits.

REFERENCES

1. Jan M Rabaey, “Digital Integrated Circuits”, Prentice Hall of India, 2002.
2. Sung-Mo Kang and Yusuf Leblebici, “CMOS Digital Integrated Circuits- Analysis and Design”, TataMcGraw Hill, 2003.
3. Neil H.E. Weste and Kamran Eshraghian, “Principles of CMOS VLSI Design”, Pearson Education, ASIA, 2nd edition, 2000.
4. J.Bhasker, B.S.Publications, “A Verilog HDL Primer”, 2nd Edition, 2001.
5. Wayne Wolf “Modern VLSI Design System on chip”, Pearson Education, 2002.

WEB LINKS

1. <http://nptel.ac.in/courses/117106092/>
2. <http://nptel.ac.in/courses/Webcourse-contents/IIT Bombay/VLSI%20Design/Course%20Objective.html>
3. <https://www.youtube.com/watch?v=9SnR3M3CIm4>

PVL15105 SOLID STATE DEVICE MODELING AND SIMULATION 3 2 0 4

OBJECTIVES:

- To know the basic semiconductor physics.
- To understand the basic concepts bipolar device modeling.
- To know the operation of MOSFET modeling.
- To understand the Operation parameter measurement.
- To study the functions characteristics of optoelectronic device modeling.

UNIT I SEMICONDUCTOR PHYSICS 9+6

Quantum Mechanical Concepts, Carrier Concentration, Transport Equation, Band gap, Mobility and Resistivity, Carrier Generation and Recombination, Avalanche Process, Noise Sources-Diodes : Forward and Reverse biased junctions – Reverse bias breakdown – Transient and AC conditions – Static and Dynamic behavior- Small and Large signal models – SPICE model for a Diode – Temperature and Area effects on Diode Model Parameters.

UNIT II BIPOLAR DEVICE MODELING 9+6

Transistor Models: BJT – Transistor Action – Minority carrier distribution and Terminal currents - Switching- Eber - Molls and Gummel Poon Model, SPICE modeling - temperature and area effects.

UNIT III MOSFET MODELING 9+6

OS Transistor – NMOS, PMOS – MOS Device equations - Threshold Voltage – Second order effects - Temperature Short Channel and Narrow Width Effect, Models for Enhancement, Depletion Type MOSFET, CMOS Models in SPICE.

UNIT IV PARAMETER MEASUREMENT 9+6

Bipolar Junction Transistor Parameter – Static Parameter Measurement Techniques – Large signal parameter Measurement Techniques, Gummel Plots, MOSFET: Long and Short Channel Parameters, Measurement of Capacitance.

UNIT V OPTOELECTRONIC DEVICE MODELING 9+6

Static and Dynamic Models, Rate Equations, Numerical Technique, Equivalent Circuits, Modeling of LEDs, Laser Diode and Photo detectors.

TOTAL: 45+30 PERIODS

OUTCOMES:

After Completion of the course, the students will be able to:

- Know the fundamental of semiconductor physics.
- Understand BJT modeling.
- Understand and design MOSFET modeling.
- Analyze optoelectronic device modeling methods.

REFERENCES

1. Ben.G.Streetman, “Solid State Devices”, Prentice Hall, 1997.
2. Giuseppe Massobrio and Paolo Antognetti, “Semiconductor Device Modeling with SPICE”, Second Edition, McGraw-Hill Inc, New York, 1993.
3. Mohammed Ismail & Terri Fiez “Analog VLSI-Signal & Information Processing” 1stedition,Tata McGraw Hill Publishing Company Ltd 2001.
4. Roulston E.J., “Bipolar Semiconductor Devices”, Mc-Graw Hill, 1990.
5. Tor.A.Fijedly, “Introduction to Device Modelling and Circuit Simulation”, Wiley-interscience, 1997.

WEB LINKS

1. <https://www.youtube.com/watch?v=Kp-jS6NHsB8&list=PLF178600D851B098F>
2. <http://nptel.ac.in/courses/117106091/>

OBJECTIVES:

- To understand HDL and design circuits using it.
- To gain the ability to write the programs in VHDL and Verilog for modeling digital circuits
- To study and verify the combinational and sequential logic circuits with various levels of modeling and EDA Tools.
- To know importance of basic electronics involved in the design of MOS circuits.

LIST OF EXPERIMENTS

1. Modeling of Sequential Digital system using VHDL.
2. Modeling of Sequential Digital system using Verilog.
3. Writing Test Benches Using Verilog / VHDL
4. Design and Implementation of ALU using FPGA.
5. Simulation of NMOS and CMOS circuits using SPICE.
6. Design of Static and Dynamic Logic Circuits
7. Modeling of MOSFET using C.
8. Implementation of FFT, Digital Filters.
9. Implementation of DSP algorithms using software package.
10. Implementation of MAC Unit using FPGA.

TOTAL: 60 PERIODS**OUTCOMES:****After Completion of the course, the students will be able to:**

- Make models of transistor circuits and simulate them for various operational requirements.
- Design the different types of multiplier using EDA Tool.
- Design the FIR Filter using EDA Tool.
- Analyze and design the VLSI circuits.

PVL15201 ANALYSIS AND DESIGN OF ANALOG INTEGRATED CIRCUITS 3 2 0 4

OBJECTIVES:

- To understand the operation of integrated circuits.
- To analyze various devices in circuit configuration of integrated circuit.
- To impart in-depth knowledge about CMOS operational amplifier.
- To explore the concepts of PLL and its application.
- To learn fundamental concepts on ADC and DAC converters.

UNIT I MODELS FOR INTEGRATED CIRCUIT ACTIVE DEVICES

9+6

Depletion region of a PN junction – large signal behavior of bipolar transistors- small signal model of bipolar transistor- large signal behavior of MOSFET- small signal model of the MOS transistors- short channel effects in MOS transistors – weak inversion in MOS transistors- substrate current flow in MOS transistor

UNIT II CIRCUIT CONFIGURATION FOR LINEAR IC

9+6

Current sources, Analysis of difference amplifiers with active load using BJT and FET, supply and temperature independent biasing techniques, voltage references - Output stages: Emitter follower, source follower and Push pull output stages.

UNIT III CMOS OPERATIONAL AMPLIFIERS

9+6

Buffered operational amplifiers-High speed and frequency operational amplifiers-Differential output operational amplifiers-Microwave operational amplifiers - Low noise operational amplifiers - Low voltage operational amplifiers.

UNIT IV ANALOG MULTIPLIER AND PLL

9+6

Analysis of four quadrant and variable trans conductance multiplier, voltage controlled oscillator, closed loop analysis of PLL, Monolithic PLL design in integrated circuits: Sources of noise- Noise models of Integrated-circuit Components – Circuit Noise Calculations – Equivalent Input Noise Generators – Noise Bandwidth – Noise Figure and Noise Temperature.

UNIT V DIGITAL-ANALOG AND ANALOG-DIGITAL CONVERTERS

9+6

Introduction and characterization of DAC-Parallel DAC-Extending the resolution of parallel DAC-Serial DAC-Introduction and characterization of ADC-Serial ADC-Medium ADC-High speed ADC.

TOTAL : 45+30 PERIODS

OUTCOMES:

After Completion of the course, the students will be able to:

- Explain basic definitions and overview of CMOS integrated circuit.
- Acquire knowledge of how circuit configuration is made for Linear IC.
- Learn and analyze the problems in operational amplifier.
- Understand noise in analog amplifier circuit from a hierarchical viewpoint.
- Apply advanced technical knowledge in MOS technology

REFERENCES

1. Gray, Meyer, Lewis, Hurst, “Analysis and design of Analog IC’s”, 4th Edition, Wiley International, 2002.
2. Behzad Razavi, “Design of Analog CMOS Integrated Circuits”, S.Chand and company ltd, 2000
3. Nandita Dasgupta, Amitava Dasgupta, “Semiconductor Devices, Modelling and Technology”, Prentice Hall of India pvt.ltd, 2004.
4. Grebene, “Bipolar and MOS Analog Integrated circuit design”, John Wiley & sons, Inc., 2003.

WEB LINKS

1. <http://nptel.ac.in/courses/117107094/>
2. <https://www.youtube.com/watch?v=WezDgErVQWU&list=PLC19EACF93A23928B>
3. <http://nptel.ac.in/courses/117106030/>

OBJECTIVES:

- To introduce the basic CAD algorithm
- To understand the Partitioning
- To study about Placement, Floor Planning
- To learn about Global, Detail routing
- To know the Modeling and synthesis in CAD flow.

UNIT I LOGIC SYNTHESIS & BASIC ALGORITHMS**9+6**

Introduction to combinational logic synthesis - Binary Decision Diagram - Hardware models for High-level synthesis - graph algorithms - computational geometry algorithms.

UNIT II PARTITIONING**9+6**

Classification of partitioning algorithms - Group migration algorithms - simulated annealing & evolution, other partitioning algorithms

UNIT III PLACEMENT, FLOOR PLANNING & PIN ASSIGNMENT**9+6**

Simulation base placement algorithms, other placement algorithms - constraint based floor planning - floor planning algorithms for mixed block & cell design - General & channel pin assignment for register minimization

UNIT IV ROUTING**9+6**

Classification of global routing algorithms - Maze routing algorithm - line probe algorithm - Steiner Tree based algorithms - ILP based approaches-classification of routing algorithms - single layer routing algorithms, two layer channel routing algorithms, three layer channel routing algorithms, and switchbox routing algorithms.

UNIT V MODELING AND SYNTHESIS**9+6**

High level Synthesis - Hardware models - Internal representation - Allocation - assignment and scheduling - Simple scheduling algorithm - Assignment problem - High level transformations.

TOTAL: 45+30 PERIODS

OUTCOMES:

After Completion of the course, the students will be able to:

- Learn the Fundamentals of basic algorithm in CAD.
- Study the different partitioning algorithm.
- Understand the floor planning and placement algorithm.
- Learn about different routing algorithms.
- Know about modeling and synthesis techniques of CAD.

REFERENCES

1. Chrysostomos Nicopoulos, Vijaykrishnan Narayanan, Chita R.Das, “Networks-on-Chip “Architectures - A Holistic Design Exploration”, Springer.
2. Sudeep Pasricha and Nikil Dutt, “On-Chip Communication Architectures: System on Chip Interconnect”, Morgan Kaufmann Publishers © 2008.
3. Frank Ghenassia, “Transaction Level Modeling with SystemC: TLM Concepts and Applications for Embedded Systems”, Springer © 2005 (281 pages), ISBN:9780387262321.
4. Luca Benini and Giovanni De Micheli, “Networks on Chips: Technology and Tools”, Morgan Kaufmann Publishers © 2006 (408 pages), ISBN:9780123705211.
5. Fayezegebali, Haythamelmiligi, Hqhahed Watheq E1-Kharashi “Networks-on-Chips theory and practice”, CRC press.

WEB LINKS

1. <https://www.youtube.com/watch?v=jZ6LAcHmvng>
2. www.ece.rice.edu/~kmram/elec523/Notes/general-introduction.pdf
3. <http://nptel.ac.in/courses/106105034/>

OBJECTIVES:

- To understand the basic concepts of DSP algorithms.
- To know about the folding & unfolding concepts.
- To analyze the various pipelining and parallel processing techniques.
- To study the retiming and unfolding algorithms for various DSP applications.
- To analyze the concept of various filters.

UNIT I DSP SYSTEMS 9+6

Introduction To DSP Systems -Typical DSP algorithms; Iteration Bound – data flow graph representations, loop bound and iteration bound, Longest path Matrix algorithm; Pipelining and parallel processing – Pipelining of FIR digital filters, parallel processing, pipelining and parallel processing for low power.

UNIT II RETIMING, FOLDING AND UNFOLDING 9+6

Retiming - definitions and properties Retiming techniques; Unfolding – an algorithm for Unfolding, properties of unfolding, sample period reduction and parallel processing application; Folding – Folding transformation – Register minimizing techniques – Register minimization in folded architectures.

UNIT III FAST CONVOLUTION 9+6

Fast convolution – Cook-Toom algorithm, modified Cook-Took algorithm –Iterated Convolution – Cyclic Convolution; Pipelined and parallel recursive and adaptive filters – inefficient/efficient single channel interleaving, Look- Ahead pipelining in first- order IIR filters, Look-Ahead pipelining with power-of-two decomposition parallel processing of IIR filters, combined pipelining and parallel processing of IIR filters, pipelined adaptive digital filters, relaxed look-ahead, pipelined LMS adaptive filter.

UNIT IV BIT-LEVEL ARCHITECTURE AND SYSTOLIC ARRAY DESIGN 9+6

Bit-Level Arithmetic Architectures- parallel multipliers with sign extension, parallel carry-ripple array multipliers, parallel carry-save multiplier, 4x 4 bit Baugh- Wooley carry-save multiplication tabular form and implementation, design of Lyon's bit-serial multipliers using Horner's rule, bit-serial FIR filter, CSD representation, CSD multiplication using Horner's rule for precision improvement. Systolic array design methodology – FIR systolic Arrays – selection of scheduling vector-matrix multiplication and 2D systolic array design-Systolic design for space representations containing Delays

UNIT V PROGRAMMING DIGITAL SIGNAL PROCESSORS

9+6

Synchronous, Wave and asynchronous pipelining- synchronous pipelining and clocking styles, clock skew in edge-triggered single-phase clocking, two-phase clocking, wave pipelining, asynchronous pipelining bundled data versus dual rail protocol; Programming Digital Signal Processors – general architecture with important features; Low power Design – needs for low power VLSI chips, charging and discharging capacitance, short-circuit current of an inverter, CMOS leakage current, basic principles of low power design.

TOTAL: 45+30 PERIODS

OUTCOMES:

After Completion of the course, the students will be able to:

- Learn DSP algorithms.
- Understand and analyse the concept of pipelining and other processing for DSP applications
- Study about programming of digital signal processors.

REFERENCES

1. Keshab K.Parhi, “VLSI Digital Signal Processing systems, Design and implementation”, Wiley, Inter Science, 1999.
2. Gary Yeap, “Practical Low Power Digital VLSI Design”, Kluwer Academic Publishers, 1998.
3. Mohammed Ismail and Terri Fiez, “Analog VLSI Signal and Information Processing”, Mc Graw-Hill, 1994.
4. Jose E. France and Yannis T sividis,“Design of Analog - Digital VLSI Circuits for Telecommunication and Signal Processing”, Prentice Hall, 1994.
5. S.Y. Kung, H.J. White House, T. Kailath, “VLSI and Modern Signal Processing”, Prentice Hall, 1985.

WEB LINKS

1. <http://nptel.ac.in/courses/117102060/>
2. https://www.youtube.com/watch?v=dM1y6ZfQkDU&list=PLqZ3SwXz_MIHEYL7x1psc2x6wfPl yg53P
3. <http://nptel.ac.in/courses/117101001/>

OBJECTIVES:

- To Implement 8 Bit ALU in FPGA / CPLD
- To Implement 4 Bit Sliced processor in FPGA / CPLD
- To Implement Elevator controller using embedded microcontroller
- To Implement Alarm clock controller using embedded microcontroller
- To Implement Model train controller using embedded microcontroller
- To Implement the System design using PLL

LIST OF EXPERIMENTS

1. Implementation of 8 Bit ALU in FPGA / CPLD.
2. Implementation of 4 Bit Sliced processor in FPGA / CPLD
3. Implementation of Elevator controller using embedded microcontroller.
4. Implementation of Alarm clock controller using embedded microcontroller.
5. Implementation of model train controller using embedded microcontroller.
6. System design using PLL.
7. Design and simulation of circuits for gate level event driven simulation.
8. Design and simulation of BIST architectures
9. Design of Minimum Spanning Tree and Partitioning Algorithm.
10. Mini Project

TOTAL: 60 PERIODS**OUTCOMES:****After Completion of the course, the students will be able to:**

- Write HDL code for basic as well as advanced digital integrated circuits.
- Import the logic modules into FPGA Boards.
- Synthesize Place and Route the digital IPs.
- Design, Simulate and Extract the layouts of Analog IC Blocks using EDA tools.

ELECTIVE I

PVL15151 LOW POWER VLSI DESIGN 3 00 3

OBJECTIVES:

- To know the sources of power consumption in CMOS circuits
- To understand the various power reduction techniques and the power estimation methods.
- To study the design concepts of low power circuits.

UNIT I POWER DISSIPATION IN CMOS 9

Hierarchy of limits of power – Sources of power consumption – Physics of power dissipation in CMOS FET devices- Basic principle of low power design.

UNIT II POWER OPTIMIZATION 9

Logical level power optimization – Circuit level low power design – Circuit techniques for reducing power consumption in adders and multipliers CMOS Circuits design styles, Adders, Multipliers

UNIT III DESIGN OF LOW POWER CMOS CIRCUITS 9

Computer Arithmetic techniques for low power systems – Reducing power consumption in memories – Low power clock, Interconnect and layout design – Advanced techniques – Special techniques

UNIT IV POWER ESTIMATION 9

Power estimation techniques – Logic level power estimation – Simulation power analysis – Probabilistic power analysis- Random Logic signals – Probabilistic power analysis techniques

UNIT V SYNTHESIS AND SOFTWARE DESIGN FOR LOW POWER 9

Synthesis for low power –Behavioral level transforms- Software design for low power– Sources of software power Dissipation – Software Power Estimation –Software Power optimization

TOTAL: 45 PERIODS

OUTCOMES:

After Completion of the course, the students will be able to:

- Learn the basic concepts and principles of CMOS.
- Learn the Techniques of reducing power consumption
- Understand advanced and special techniques for low power systems
- Learn about the techniques involved in power estimation

- Know about software design for low power.

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1. K.Roy and S.C. Prasad , “Low Power CMOS VLSI circuit design”, Wiley,2000
2. DimitriosSoudris, ChirstianPignet, Costas Goutis, “Designing CMOS Circuits For Low Power”, Kluwer,2002
3. J.B. Kuo and J.H Lou, “Low voltage CMOS VLSI Circuits”,Wiley 1999.
4. A.P.Chandrakasan and R.W. Broadersen, “Low power digital CMOS design”, Kluwer,1995.
5. Gary Yeap, “Practical low power digital VLSI design”, Kluwer,1998.

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2. textofvideo.nptel.iitm.ac.in/106105034/lec1.pdf
3. www.cpdee.ufmg.br/~frank/lectures/Sill-LowPower2.ppt
4. <http://nptel.ac.in/courses/106105034/>

OBJECTIVES:

- To study the design flow of different types of ASIC.
- To familiarize the different types of programming technologies and logic devices.
- To learn the architecture of different types of FPGA.
- To understand logic synthesis and testing.
- To gain knowledge about partitioning, floor planning, placement and routing.

UNIT I ASICS, CMOS LOGIC AND ASIC LIBRARY DESIGN

9

Types of ASICs - Design flow - CMOS transistors CMOS Design rules - Combinational Logic Cell – Sequential logic cell - Data path logic cell - Transistors as Resistors - Transistor Parasitic Capacitance- Logical effort –Library cell design - Library architecture.

UNIT II PROGRAMMABLE ASICS, PROGRAMMABLE ASIC LOGIC CELLS AND PROGRAMMABLEASIC I/O Cells

9

Anti fuse - static RAM - EPROM and EEPROM technology - PREP benchmarks - Actel ACT - Xilinx LCA –Altera FLEX - Altera MAX DC & AC inputs and outputs - Clock & Power inputs - Xilinx I/O blocks.

UNIT III PROGRAMMABLE ASIC INTERCONNECT, PROGRAMMABLE ASIC DESIGN SOFTWARE AND LOW LEVEL DESIGN ENTRY

9

Actel ACT -Xilinx LCA - Xilinx EPLD - Altera MAX 5000 and 7000 - Altera MAX 9000 - Altera FLEX – Design systems - Logic Synthesis - Half gate ASIC -Schematic entry - Low level design language - PLA tools -EDIF- CFI design representation.

UNIT IV LOGIC SYNTHESIS, SIMULATION AND TESTING

9

Verilog and logic synthesis -VHDL and logic synthesis - types of simulation -boundary scan test - fault simulation - automatic test pattern generation

UNIT VASIC CONSTRUCTION, FLOOR PLANNING, PLACEMENT AND ROUTING

9

System partition - FPGA partitioning - partitioning methods - floor planning - placement - physical design flow –global routing - detailed routing - special routing - circuit extraction - DRC.

TOTAL: 45 PERIODS

OUTCOMES:

After Completion of the course, the students will be able to:

- Understand different types of ASIC's.
- Know programmable ASIC's logic cell and I/O cells.
- Study the programmable ASIC interconnect and software.
- Understand logic synthesis and testing.
- Learn the concepts of placement and routing.

REFERENCES

1. M.J.S .Smith, "Application Specific Integrated Circuits", Addison -Wesley Longman Inc., 1997.
2. Farzad Nekoogar and Faranak Nekoogar, "From ASICs to SOCs: A Practical Approach", Prentice Hall PTR, 2003.
3. Wayne Wolf, "FPGA-Based System Design", Prentice Hall PTR, 2004.
4. J.Bhaskar, "A VHDL Synthesis Primer", BS Publications, 2001.
5. J.Bhaskar "VHDL Coding Styles and Methodologies", BS Publications, 2005.

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1. https://www.youtube.com/watch?v=q3po_gNaTBw&list=PLgt7vY9oZ0Wwp53Mrlg_KxQYCMGnebHXR
2. staff.fit.ac.cy/com.tk/ACOE361/Design_Flow.ppt
3. <https://www.youtube.com/watch?v=vxSvQ-IcmHM>

- Design digital systems using modern design tools.

REFERENCES

1. Janick Bergeron, “Writing Test Benches Functional Verification of HDL Models”, Springer, 2003.
2. Samir Palnitkar, “Design Verification with E”, Prentice Hall, 2003
3. T.Kropf, “Introduction to Formal Hardware Verification”, Springer Verlag, 2010.
4. Chris Spear, “System Verilog for Verification: A Guide to Learning the Test bench Language Features”, Springer, 2008.
5. Janick Bergeron, Edward Cerny, Alan Hunter and Andrew Nightingale, “Verification Methodology Manual for System Verilog”, Springer, 2005.

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1. <http://nptel.ac.in/courses/106103016/>
2. https://www.youtube.com/watch?v=crBvULemVcQ&list=PL6tk8xkG6ZQc3TNr4D_6WVQOpb1D-IdeW

OBJECTIVES:

- To study about the wired and wireless LANs and backbone networks.
- To gain depth knowledge about the routing protocol and congestion controls.
- To focus on simulation and modeling of Qualnet and NS2 simulators.

UNIT I WIRED LANS**9**

Standard Ethernet- Mac sub layer-physical layer, Bridged Ethernet, switched Ethernet, Fast Ethernet, Gigabit Ethernet. Backbone Networks Connecting devices, Hubs, Bridges, Routers, Gateway, three layer switches, Virtual LAN-SONET.

UNIT II FLOW/CONGESTION CONTROL**9**

Implementation, modeling, fairness, stability, open-loop vs. closed-loop vs. hybrid, traffic specification (LBAP, leaky-bucket), window vs. rate, hop-by-hop vs. end-to-end, implicit vs. explicit feedback, aggregate flow control, reliable multicast TCP variants (Tahoe, Reno, Vegas, New-Reno, SACK), DEC bit, Packet Pair, NETBLT, ATM Forum EERC, T/TCP

Scheduling and Buffer Management

Implementation, fairness, performance bounds, admission control, priorities, work conservation, scheduling best effort(BE) flows, scheduling guaranteed-service (GS) flows (GPS, WRR, DRR, WFQ, EDD, RCSP), aggregation, drop strategies (tail-drop, RED, WRED)

UNIT III ROUTING**9**

Implementation, stability/convergence, link-state vs. distance-vector vs. link-vector, conventional routing, Routing Information Protocol (RIP), Open Shortest Path First (OSPF), Multicast OSPF (MOSPF), Distance Vector Multicast Routing Protocol (DVMRP), BGP instability, Fair queuing, TCP congestion control, TCP variants, Random Early Detect, TCP RTT estimation, Fast retransmit, Fast recovery.

UNIT IV CONGESTION CONTROL**9**

Congestion Control-open loop-closed loop, congestion control in TCP, congestion control in Frame relay-Quality of service- Integrated Services, Resource Reservation Protocol (RSVP), Differentiated Services, Overlay Networks, Peer-to-Peer Networks, Chord.

UNIT V SIMULATION AND MODELING

9

Wide-Area Traffic Modeling, End-to-end Internet Packet Dynamics, Traffic engineering, Multi-Protocol Label Switching (MPLS), Network Simulators- NS2, OPNET, QualNet.

IP Next Generation

IP Next Layer (IPNL), IPV6 features, including transition, Mobile IPV6 operation, Models to support (WLAN) network roaming, IPV6 transition methods, Advanced IP routing and multi homing, IP Multicast.

TOTAL: 45 PERIODS

OUTCOMES:

After Completion of the course, the students will be able to:

- Identify the type of networks and protocols for a given network scenario.
- Estimate the performance and throughput of a given network.
- Design a network aimed at optimum performance.
- Understand the traffic modeling and congestion control in networks.

REFERENCES

1. Larry Peterson and Bruce Davie, "Computer Networks: A Systems Approach", Morgan Kaufmann, 2007.
2. Michael A Gallo and William M Hancock, "Computer Communications and Networking Technologies", Thomson Learning, 2002.
3. Jim Kurose and Keith Ross, "Computer Networking: A Top-Down Approach Featuring the Internet", Addison- Wesley, 2004.
4. William Stallings, "Data and Computer Communications", Prentice Hall, 2006.
5. Behrouz Forouzan, "Data communications and Networking", TMH, 2007

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2. <http://nptel.ac.in/courses/117105076/>

ELECTIVE II

PVL15251

CMOS VLSI DESIGN

3 0 0 3

OBJECTIVES:

- To understand the basic CMOS circuits.
- To learn the CMOS process technology.
- To study the techniques of chip design using programmable devices.
- To learn the concepts of designing VLSI subsystems.
- To focus on the concepts of modeling a digital system using Hardware Description Language.

UNIT I MOS TRANSISTOR THEORY

9

Introduction to I.C Technology- Basic MOS transistors - Threshold Voltage -Body effect - Basic D.C. Equations - Second order effects - MOS models - Small signal A.C characteristics - The complementary CMOS inverter - DC characteristics - Static Load MOS inverters - The differential inverters - Transmission gate.

UNIT-II CMOS PROCESSING TECHNOLOGY

9

Silicon semiconductor technology - Wafer processing, Oxidation, epitaxy, deposition, Ion implantation - CMOS technology – n-well, p-well process - Silicon on insulator - CMOS process enhancement - Interconnect and circuit elements. Layout design rules - Latchup

UNIT III CIRCUIT CHARACTERISTICS AND PERFORMANCE ESTIMATION

9

Resistance estimation - Capacitance estimation. MOS capacitor characteristics -Device capacitances - Diffusion capacitance Routing capacitance - Distributed RC effects - Inductance - Switching characteristics Rise time - Fall time. Delay time. Empirical delay models - Gate delays. CMOS gate transistor sizing - Power dissipation. Scaling of MOS transistor dimensions

UNIT IV CMOS CIRCUIT AND LOGIC DESIGN

9

CMOS Logic gate design - Fan in and fan out. Typical CMOS NAND and NOR delays - Transistor sizing - CMOS logic structures - Complementary logic - BICMOS logic - Pseudo nMOS logic - Dynamic CMOS logic -Clocked CMOS logic - Pass transistor logic. CMOS domino logic.NP domino logic - Dual rail logic with suitable examples - Cascade voltage switch logic. Source follower pull up Logic (SFPL). Clocking strategies –I/O structures -Comparison of circuit families`

UNIT V CMOS SUBSYSTEM DESIGN

9

Data path operations - Addition/subtraction - Parity generators – Comparators - Zero/one detectors - Binary Counters - ALUs, Design of multipliers: Parallel Multipliers, Array, 2's Complement, Booth - Braun – Baugh - Wooley - Wallace tree, Dadda Multipliers, Serial Multiplication – Shifters - Memory elements - RWM, ROM, Content Addressable Memory. Control: FSM, PLA Control Implementation.

TOTAL: 45 PERIODS

OUTCOMES:

After Completion of the course, the students will be able to:

- Differentiate the ideal and non-ideal characteristics of MOSFET.
- Know various methodologies to fabricate an IC.
- Understand the switching characteristics and power reduction techniques.
- Know the circuit families.
- Design and analyze different CMOS subsystems.

REFERENCES

1. Neil.H.E. Weste and K.Eshragian, “Principles of CMOS VLSI Design”, 2nd Edition. Addison-Wesley, 2000.
2. Douglas a. Pucknell and K.Eshragian., “Basic VLSI Design” 3rd Edition. PHI, 2000.
3. R. Jacob Baker, Harry W. LI., & David K. Boyce., “CMOS Circuit Design”, 3rd Indian reprint, PHI, 2000.
4. N.Weste and D.Harris, “Introduction to CMOS VLSI design”, Addison-,3rd Edition,2004.

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1. <http://nptel.ac.in/courses/Webcourse-contents/IIT-Bombay/VLSI%20Design/Course%20Objective.htm>
2. https://www.youtube.com/watch?v=4It_j_Y944o
3. <https://www.youtube.com/watch?v=9SnR3M3CI4>

OBJECTIVES:

- To acquire basic knowledge about SRAMs and DRAMs
- To study about Non Volatile memories and their types
- To know about fault modeling and testing in memories
- To introduce the concept of reliability and radiation effects in memories
- To gather knowledge about packaging technologies for memories

UNIT I RANDOM ACCESS MEMORY TECHNOLOGIES 9**Static random access memories (SRAMs):**

SRAM Cell Structures-MOS SRAM Architecture-MOS SRAM Cell and Peripheral Circuit Operation-Bipolar SRAM Technologies-Silicon on Insulator (SOI) Technology-Advanced SRAM Architectures and Technologies-Application Specific SRAMs.

Dynamic Random Access Memories (DRAMs):

DRAM Technology Development-CMOS DRAMs-DRAMs Cell Theory and Advanced Cell Structures-BiCMOS, DRAMs-Soft Error Failures in DRAMs-Advanced DRAM Designs and Architecture-Application Specific DRAMs.

UNIT II NONVOLATILE MEMORIES 9

Masked Read-Only Memories (ROMs)-High Density ROMs-Programmable Read-Only Memories (PROMs)-Bipolar PROMs-CMOS PROMs-Erasable (UV) - Programmable Road-Only Memories (EPROMs)-Floating-Gate EPROM Cell-One-Time Programmable (OTP) EPROMS-Electrically Erasable PROMs (EEPROMs)-EEPROM Technology And Architecture-Nonvolatile SRAM-Flash Memories (EPROMs or EEPROM)-Advanced Flash Memory Architecture.

**UNIT III MEMORY FAULT MODELING, TESTING, AND MEMORY DESIGN FOR
TESTABILITY AND FAULT TOLERANCE 9**

RAM Fault Modeling, Electrical Testing, Pseudo Random Testing-Megabit DRAM Testing-Nonvolatile Memory Modeling and Testing-IDDQ Fault Modeling and Testing-Application Specific Memory Testing

UNIT IV SEMICONDUCTOR MEMORY RELIABILITY AND RADIATION EFFECTS 9

General Reliability Issues-RAM Failure Modes and Mechanism-Nonvolatile Memory Reliability-Reliability Modeling and Failure Rate Prediction-Design for Reliability-Reliability Test Structures-

Reliability Screening and Qualification- RAM Fault Modeling, Electrical Testing, Pseudo Random Testing-Megabit DRAM Testing-Nonvolatile Memory Modeling and Testing-IDDQ Fault Modeling and Testing-Application Specific Memory Testing

UNIT V ADVANCED MEMORY TECHNOLOGY

9

Ferroelectric Random Access Memories (FRAMs)-Gallium Arsenide (GaAs) FRAMs-Analog Memories- Magneto-resistive Random Access Memories (MRAMs)-Experimental Memory Devices -Memory Hybrids and MCMs (2D)-Memory Stacks and MCMs (3D)-Memory MCM Testing and Reliability Issues-Memory Cards-High Density Memory Packaging Future Directions.

TOTAL: 45 PERIODS

OUTCOMES:

After Completion of the course, the students will be able to:

- Learn the technology behind Random Access Memories
- Understand the Nonvolatile memories
- Know about fault modeling and testing of memories
- Learn the concepts of memory reliability and packaging technologies

REFERENCES

1. Ashok K. Sharma, “Semiconductor Memories: Technology, Testing, and Reliability”, Wiley-IEEE Press, 2002.
2. Ashok K. Sharma, “Semiconductor Memories, Two-Volume Set”, Wiley-IEEE Press, 2003.
3. Ashok K. Sharma, “Semiconductor Memories: Technology, Testing, and Reliability”, Prentice Hall of India, 1997.
4. Brent Keeth, R. Jacob Baker, “DRAM Circuit Design: A Tutorial”, Wiley-IEEE Press, 2000.
5. Betty Prince, “High Performance Memories: New Architecture DRAMs and SRAMs - Evolution and Function”, Wiley, 1999.

WEB LINKS

1. <https://www.youtube.com/watch?v=omxQsvenf9o>
2. <https://www.youtube.com/watch?v=1vMcBQCWRgo>
3. vlsi.daiict.ac.in/files/Memories-Daiict.ppt

OBJECTIVES:

- To understand the purification of Silicon in different technologies.
- To impart in-depth knowledge about photolithography and etching process.
- To acquire knowledge about deposition, diffusion and ion implantation of different layers.
- To know various methodologies to fabricate an IC.
- To understand the different packaging techniques of VLSI devices.

UNIT I MATERIAL PROPERTIES, CRYSTAL GROWTH, WAFER PREPARATION, EPITAXY AND OXIDATION 9

Crystal structure- axes & planes, Crystal defects-Point defects & dislocations Crystal growth- Bridgman, Czochralski crystal growing, Silicon Shaping, processing consideration, Vapor phase Epitaxy, Molecular Beam Epitaxy, Silicon on Insulators, Epitaxial Evaluation, Growth Mechanism and kinetics, Thin Oxides, Oxidation Techniques and Systems, Oxide properties, Redistribution of Dopants at interface, Oxidation of Poly Silicon, Oxidation induced Defects.

UNIT II LITHOGRAPHY AND RELATIVE PLASMA ETCHING 9

Optical Lithography, Electron Lithography, X-Ray Lithography, Ion Lithography, Plasma properties, Feature Size control and Anisotropic Etch mechanism, relative Plasma Etching techniques and Equipment's.

UNIT III DEPOSITION, DIFFUSION, ION IMPLEMENTATION AND METALLIZATION 9

Deposition process, Polysilicon, plasma assisted Deposition, Models of Diffusion in Solids, Fick's one dimensional Diffusion Equation – Atomic Diffusion Mechanism – Measurement techniques - Range theory- Implant equipment. Annealing Shallow junction – High energy implantation – Physical vapour deposition – Patterning.

UNIT IV PROCESS SIMULATION AND VLSI PROCESS INTEGRATION 9

Ion implantation – Diffusion and oxidation – Epitaxy – Lithography – Etching and Deposition- NMOS IC Technology – CMOS IC Technology – MOS Memory IC technology - Bipolar IC Technology – IC Fabrication.

Unit V Packaging of VLSI Devices

9

Package types – banking design consideration – VLSI assembly technology – Package fabrication technology.

TOTAL: 45 PERIODS

OUTCOMES:

After Completion of the course, the students will be able to:

- Learn about various metallization techniques
- Create three-dimensional device structures and devices.
- Know methodology to fabricate an IC's.
- Understand and design advanced electronics systems (Analog and Digital Systems).
- Conduct experiments, analyze and interpret data.

REFERENCES

1. S.M.Sze, “VLSI Technology”, Mc.GrawHill Second Edition. 1998.
1. Amarmukherjee, “Introduction to NMOS and CMOS VLSI System design”, Prentice Hall India.2000.
2. James D Plummer, Michael D. Deal, Peter B.Griffin, “Silicon VLSI Technology: fundamentals practice and Modeling”, Prentice Hall India.2000.
3. Wai Kai Chen, “VLSI Technology”, CRC press,2003.

WEB LINKS

1. <http://nptel.ac.in/courses/117106093/>
2. <https://www.youtube.com/watch?v=9SnR3M3CIm4&list=PL7F0047F236A6E731>
3. https://www.youtube.com/watch?v=_gpEBYUnj6k

OUTCOMES:

After Completion of the course, the students will be able to:

- Design and implement of advanced microprocessor.
- Know about the high performance RISC and CISC architecture.
- Perform PIC microcontroller programming.
- Know about the various special purpose processors.

REFERENCES

1. Daniel Tabak , “Advanced Microprocessors”, McGraw Hill.Inc., 1995
2. Steve Furber, “ARM System –On –Chip architecture”, Addison Wesley, 2000.
3. Gene.H.Miller, “Micro Computer Engineering”, Pearson Education, 2003.
4. Valvano, “Embedded Microcomputer Systems”, Thomson Asia Pvt Ltd first reprint 2001.
5. Munir Bannaoura, Rudan Bettelheim and Richard Soja, “ColdFire Microprocessors and Microcontrollers”, AMT Publishing, 2007

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2. <https://www.youtube.com/watch?v=liRPtvj7bFU&list=PL7C177BFA6F3C6544>
3. cache.freescale.com/files/32bit/doc/prod_brief/MCF5251PB.pdf

ELECTIVE III

PVL15351

ANALOG VLSI DESIGN

3 0 0 3

OBJECTIVES:

- To acquire basic knowledge about CMOS circuit techniques and amplifier design
- To study about BICMOS circuits and signal processing
- To understand the concept behind A/D Converters and analog sensors
- To introduce the concept of testing of Analog VLSI circuits
- To gather knowledge about statistical modeling and simulation of analog circuits

UNIT I CMOS CIRCUIT TECHNIQUES, CONTINUOUS TIME AND LOW VOLTAGE SIGNAL PROCESSING 9

Mixed-Signal VLSI Chips-Basic CMOS Circuits-Basic Gain Stage-Gain Boosting Techniques-Super MOS Transistor- Primitive Analog Cells-Linear Voltage-Current Converters-MOS Multipliers and Resistors-CMOS, Bipolar and Low-Voltage BiCMOS Op- Amp Design-Instrumentation Amplifier Design-Low Voltage Filters.

UNIT II BICMOS CIRCUIT TECHNIQUES, CURRENT -MODE SIGNAL PROCESSING AND NEURAL INFORMATION PROCESSING 9

Continuous-Time Signal Processing-Sampled-Data Signal Processing-Switched-Current Data Converters- Practical Considerations in SI Circuits Biologically-Inspired Neural Networks - Floating - Gate, Low-Power Neural Networks-CMOS Technology and Models- Design Methodology-Networks-Contrast Sensitive Silicon Retina.

UNIT III ANALOG CMOS SUB CIRCUITS 9

CMOS Amplifiers MOS switch-MOS diode and active resistor-Current sinks and sources-Current mirrors-Current and voltage References:-Band gap References:-Invertors-Differential amplifiers - Cascode amplifiers – Current amplifiers - Output amplifiers- High gain amplifiers architectures

UNIT IV DESIGN FOR TESTABILITY AND ANALOG VLSI INTERCONNECTS 9

Fault modeling and Simulation - Testability-Analysis Technique-Ad Hoc Methods and General Guidelines-Scan Techniques-Boundary Scan-Built-in Self Test-Analog Test Buses- Design for Electron - Beam Testability-Physics of Interconnects in VLSI-Scaling of Interconnects-A Model for Estimating Wiring Density-A Configurable Architecture for Prototyping Analog Circuits.

Unit V DIGITAL TO ANALOG AND ANALOG TO DIGITAL CONVERTERS

9

Introduction and characterization of DAC-Parallel DAC-Extending the resolution of parallel DAC-Serial DAC- Introduction and characterization of ADC-Serial ADC-Medium ADC-High speed ADC.

TOTAL: 45 PERIODS

OUTCOMES:

After Completion of the course, the students will be able to:

- Learn the CMOS circuit design and low voltage signal processing
- Understand the basic BICMOS circuit techniques and models.
- Know about sampled data analog filters and A/D Converters
- Perform the statistical modeling and simulate the analog circuits

REFERENCES

1. Mohammed Ismail, Terri Fief, “Analog VLSI signal and Information Processing”, McGraw- Hill International Editons, 1994.
2. Malcom R.Haskard, Lan C.May, “Analog VLSI Design - NMOS and CMOS”, Prentice Hall, 1998.
3. Randall L Geiger, Phillip E. Allen, Noel K.Strader, “VLSI Design Techniques for Analog and Digital Circuits”, Mc Graw Hill International Company, 1990.
4. Jose E.France, Yannis Tsvividis, “Design of Analog-Digital VLSI Circuits for Telecommunication and signal Processing”, Prentice Hall, 1994.

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2. <https://www.youtube.com/watch?v=WDo58OseTJw>
3. uhaweb.hartford.edu/ilumokanw/Intro567.ppt

OBJECTIVES:

- To introduce the basic concepts of VLSI technology
- To study the concepts of placement
- To educate about routing
- To learn about issues in circuit layout
- To introduce generation and compaction

UNIT I VLSI TECHNOLOGY**9**

Layout Rules-Circuit abstraction Cell generation using programmable logic array transistor chaining, Wein Berger arrays and gate matrices-layout of standard cells gate arrays and sea of gates, field programmable gate array(FPGA)-layout methodologies-Packaging-Computational Complexity-Algorithmic Paradigms.

UNIT II PLACEMENT USING TOP-DOWN APPROACH**9**

Partitioning: Approximation of Hyper Graphs with Graphs, Kernighan-Lin Heuristic- Ratio cut- partition with capacity and I/O constraints - Floor planning: Rectangular dual floor planning- hierarchical approach- simulated annealing- Floor plan sizing- Placement: Cost function- force directed method- placement by simulated annealing- partitioning placement

UNIT III ROUTING USING TOP DOWN APPROACH**9**

Fundamentals: Maze Running- line searching- Steiner trees Global Routing: Sequential Approaches- hierarchical approaches- multi-commodity flow based techniques-Randomized Routing- One Step approach- Integer Linear Programming Detailed Routing: Channel Routing- Switch box routing.

UNIT IV PERFORMANCE ISSUES IN CIRCUIT LAYOUT**9**

Delay Models: Gate Delay Models- Models for interconnected Delay- Delay in RC trees. Timing – Driven Placement: Zero Stack Algorithm- Weight based placement- Linear Programming Approach Timing Driving Routing: Delay Minimization- Clock Skew Problem- Buffered Clock Trees. Minimization: constrained via Minimization- unconstrained via Minimization- Other issues in minimization.

UNIT VSINGLE LAYER ROUTING, CELL GENERATION AND COMPACTION 9

Planar subset problem (PSP)- Single layer global routing- Single Layer Global Routing- Single Layer detailed Routing- Wire length and bend minimization technique – Over The Cell (OTC) Routing- Multiple chip modules(MCM)- Programmable Logic Arrays- Transistor chaining- Wein Burger Arrays- Gate matrix layout- 1D compaction- 2D compaction.

TOTAL: 45 PERIODS

OUTCOMES:

After Completion of the course, the students will be able to:

- Learn the Basic VLSI Concepts
- Learn the working of placement using top-down approach
- Know about the concepts of routing
- Learn about performance issues in Layout
- Know about generation and compaction of cell

REFERENCES

1. Ban Wong, Anurag Mittal, Yu Cao, Greg Starr, “Nano CMOS Circuit and Physical Design”, Wiley-IEEE press, 2004.
2. Sarafzadeh, C.K. Wong, “An Introduction to VLSI Physical Design”, Mc Graw Hill International Edition 1995.
3. Preas M. Lorenzatti, “Physical Design and Automation of VLSI systems”, The BenjaminCummins Publishers, 1998.
4. Naveed A. Sherwani, “Algorithm for VLSI Physical Design Automation”, 3rd Edition Springer, 1998.
5. Sadiq M. Sait, Habib Youssef, “VLSI Physical Design Automation, Theory and Practice”, World Scientific Publishing Company, 1st Edition,1999.

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2. <http://nptel.ac.in/courses/117106093/>
3. <https://www.youtube.com/watch?v=lgNjvFNyMfI>

UNIT IV ADAPTIVE RESONANCE THEORY

9

Noise-Saturation Dilemma - Solving Noise-Saturation Dilemma – Recurrent On-center –Off-surround Networks – Building Blocks of Adaptive Resonance – Substrate of Resonance Structural Details of Resonance Model – Adaptive Resonance Theory – Applications.

UNIT V SELF ORGANIZING MAPS AND NEOCOGNITRON

9

Self-organizing Map – Maximal Eigenvector Filtering – Sanger’s Rule – Generalized Learning Law – Competitive Learning - Vector Quantization – Mexican Hat Networks - Self-organizing Feature Maps – Applications. Architecture of Neocognitron – Data processing and performance of Neocognitron - Architecture of spatio – temporal networks for speech recognition.

TOTAL: 45 PERIODS

OUTCOMES:

After Completion of the course, the students will be able to:

- Understand the basics of neural networks.
- Know the concepts of radial basis functions.
- Learn about bidirectional associative memory.
- Understand the principles of resonance theory.
- Learn about self organizing maps.

REFERENCES:

1. Satish Kumar, “Neural Networks: A Classroom Approach”, Tata McGraw-Hill Publishing Company Limited, New Delhi, 2004.
2. Simon Haykin, “Neural Networks: A Comprehensive Foundation”, 2ed., Addison Wesley Longman (Singapore) Private Limited, Delhi, 2001.
3. James A. Freeman and David M. Skapura, “Neural Networks Algorithms, Applications, and Programming Techniques”, Pearson Education 2003.
4. Simon Haykin, “Neural Networks: A Comprehensive Foundation”, 2nd Edition, Prentice Hall India, 2002.
5. Martin T. Hagan, Howard B. Demuth, and Mark Beale, “Neural Network Design”, Thomson Learning, New Delhi, 2003.

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2. <http://nptel.ac.in/courses/117105084/>
3. www.cse.iitd.ac.in/~saroj/AI/ai2013/L22.ppt

OUTCOMES:

After Completion of the course, the students will be able to:

- Acquire knowledge, how to analyze and design small scale combinational logic circuits using HDLs.
- Learn to analyze the problems in digital design using HDLs.
- Understand VLSI design from a hierarchical point of view.

REFERENCES

1. Chrysostomos Nicopoulos, Vijaykrishnan Narayanan, Chita R.Das, “Networks-on-Chip Architectures A Holistic Design Exploration”, Springer,2009.
2. Fayezgeballi, Haythamelmiligi, Hqahed Watheq El-Kharashi, “Networks-on-Chips theory and practice”, CRC press, 2009.
3. Axel Jantsch, Hannu Tenhunen, “Networks on Chip”, Publisher: Springer; Soft cover reprint ofhardcover 1st ed. 2003 edition (November 5, 2010).
4. Giovanni De Micheli, Luca Benini, “Networks on Chips: Technology and Tools (Systems on Silicon)”,Publisher: Morgan Kaufmann; 1 edition (August 3, 2006).
5. Jose Flich, Davide Bertozzi, “Designing Network On-Chip Architectures in the Nanoscale Era”,(Chapman & Hall/CRC Computational Science), Publisher: Chapman and Hall/CRC; 1 edition(December 18,2010).

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2. www.eecs.wsu.edu/~pande/Journal_Papers/NoC_3D.pdf
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- Identify new areas of Nanodevice application.

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1. Rainer Waser, “Nano Electronics and Technology”, Wiley VCH, 2003.
2. Charles Poole, “Introduction to Nano Technology”, Wiley Interscience, 2003.
3. C.Wasshuber, Simon, “Simulation of Nano Structures Computational Single-Electronics”, Springer-Verlag, 2001.
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OBJECTIVES:

- To introduce the basics of probability
- To understand the concepts of reliability
- To educate about software system reliability
- To learn about testing
- To introduce reliability management

UNIT I PROBABILITY PLOTTING AND LOAD-STRENGTH INTERFERENCE 9

Statistical distribution , statistical confidence and hypothesis testing ,probability plotting techniques – Weibull, extreme value ,hazard, binomial data; Analysis of load – strength interference , Safety margin and loading roughness on reliability.

UNIT II RELIABILITY PREDICTION, MODELING AND DESIGN 9

Statistical design of experiments and analysis of variance Taguchi method, Reliability prediction, Reliability modeling, Block diagram and Fault tree Analysis, petric Nets, State space Analysis, Monte Carlo simulation, Design analysis methods – quality function deployment, load strength analysis, failure modes, effects and criticality analysis.

UNIT III ELECTRONICS AND SOFTWARE SYSTEMS RELIABILITY 9

Reliability of electronic components, component types and failure mechanisms, Electronic system reliability prediction, Reliability in electronic system design; software errors, software structure and modularity, fault tolerance, software reliability, prediction and measurement, hardware/software interfaces

UNIT IV RELIABILITY TESTING AND ANALYSIS 9

Test environments, testing for reliability and durability, failure reporting, Pareto analysis, Accelerated test data analysis, CUSUM charts, Exploratory data analysis and proportional hazards modeling, reliability demonstration, reliability growth monitoring

UNIT V MANUFACTURE AND RELIABILITY MANAGEMENT 9

Control of production variability, Acceptance sampling, Quality control and stress screening, Production failure reporting; preventive maintenance strategy, Maintenance schedules, Design for maintainability,

Integrated reliability programmes, reliability and costs, standard for reliability, quality and safety, specifying reliability, organization for reliability

TOTAL: 45 PERIODS

OUTCOMES:

After Completion of the course, the students will be able to:

- Learn the Basic probability Concepts and interference.
- Incorporate the concepts of modeling and design.
- Know about testing and analysis.
- Understand manufacture and reliability management.

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OBJECTIVES:

- To understand the basics of EMI & EMC Environment
- To know about EMI & EMC Coupling Principles
- To study the control techniques involved in Electromagnetic Interference
- To learn about EMI Specification Standards and Limits
- To know the concepts of EMI used in instrumentation system

UNIT I EMI/EMC CONCEPTS 9

EMI-EMC definitions and Units of parameters; Sources and victim of EMI; Conducted and Radiated EMI Emission and Susceptibility; Transient EMI, ESD; Radiation Hazards

UNIT II EMI COUPLING PRINCIPLES 9

Conducted, radiated and transient coupling; Common ground impedance coupling; Common mode and ground loop coupling; Differential mode coupling; Near field cable to cable coupling, cross talk; Field to cable coupling ; Power mains and Power supply coupling.

UNIT III EMI CONTROL TECHNIQUES 9

Shielding- Shielding Material-Shielding integrity at discontinuities, Filtering- Characteristics of Filters- Impedance and Lumped element filters-Telephone line filter, Power line filter design, Filter installation and Evaluation, Grounding- Measurement of Ground resistance-system grounding for EMI/EMC Cable shielded grounding, Bonding, Isolation transformer, Transient suppressors, Cable routing, Signal control. EMI gaskets

UNIT IV EMC DESIGN OF PCBS 9

EMI Suppression Cables-Absorptive, ribbon cables-Devices-Transient protection hybrid circuits, Component selection and mounting; PCB trace impedance; Routing; Cross talk control-Electromagnetic Pulse-Noise from relays and switches, Power distribution decoupling; Zoning; Grounding; VIAs connection; Terminations.

UNIT V EMI MEASUREMENTS AND STANDARDS 9

Open area test site; TEM cell; EMI test shielded chamber and shielded ferrite lined anechoic chamber; Tx/Rx Antennas, Sensors, Injectors / Couplers, and coupling factors; EMI Rx and spectrum analyzer;

Civilian standards-CISPR, FCC, IEC, EN; Military standards-MIL461E/462. Frequency assignment - spectrum conversation - British VDE standards, Euro norms standards in Japan –comparisons - EN Emission and Susceptibility standards and Specifications

TOTAL: 45 PERIODS

OUTCOMES:

After Completion of the course, the students will be able to:

- Know the concepts of EMI & EMC
- Find solution to EMI Sources
- Find solution to EMI problems in PCB level
- Measure emission immunity level from different systems to couple with different standards
- Test and implement EMI system

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1. V.P.Kodali, “Engineering EMC Principles, Measurements and Technologies”,IEEE Press, Newyork,2001
2. Henry W.Ott., “Noise Reduction Techniques in Electronic Systems”, A WileyInter Science Publications, John Wiley and Sons, Newyork, 2008.
3. Clayton R.Paul, “Introduction to Electromagnetic Compatibility”, John Wiley Publications, 2008
4. Don R.J.White Consultant Incorporate, “Handbook of EMI/EMC”, Vol I-V, 1988.
5. Bemhard Keiser, “Principles of Electromagnetic Compatibility”, 3rd Ed, Artechhouse, Norwood, 1987.

WEB LINKS

1. <https://www.youtube.com/watch?v=4hTOGc93ZTc>
2. www.irpel.org/pdf.../electromagnetic-interference-and-compatibility.pdf
3. <http://nptel.ac.in/courses/108106073/>

OBJECTIVES:

- To understand the basics of wireless communication.
- To understand the concepts of transceiver architectures.
- To introduce to the students the low power design techniques of VLSI circuits.
- To learn the design and implementation of various VLSI circuits for wireless communication systems.

UNIT I WIRELESS COMMUNICATION 9

Digital communication systems- minimum bandwidth requirement, the Shanon limit- overview of modulation schemes- classical channel- wireless channel description- path loss- multipath fading- basics of spread spectrum and spread spectrum techniques- PN sequence.

UNIT II TRANSCEIVER ARCHITECTURE 9

Transceiver design constraints- baseband subsystem design- RF subsystem design- Super heterodyne receiver and direct conversion receiver- Receiver front-end- filter design- non-idealities and design parameters- derivation of noise figure and IP3 of receiver front end.

UNIT III LOW POWER DESIGN TECHNIQUES 9

Source of power dissipation- estimation of power dissipation- reducing power dissipation at device and circuit levels- low voltage and low power operation- reducing power dissipation at architecture and algorithm levels.

UNIT IV WIRELESS CIRCUITS 9

VLSI Design of LNA-wideband and narrow band-impedance matching - Automatic Gain Control (AGC) amplifier power amplifier- Active mixer- analysis, conversion gain, distortion analysis- low frequency and high frequency case, noise - Passive mixer- sampling mixer and switching mixer- analysis of distortion, conversion gain and noise in these mixers

UNIT V VLSI DESIGN OF SYNTHESIZERS 9

VLSI design of Frequency Synthesizers (FS) – Parameters of FS - PLL based frequency synthesizer, phase detector/charge pump- dividers- VCO- LC oscillators- ring oscillator- phase noise- loop filter- description, design approaches.

TOTAL: 45 PERIODS

OUTCOMES:

After Completion of the course, the students will be able to:

- Understand the application of VLSI circuits in wireless communication.
- Gain knowledge of various architectures used in implementing wireless systems.
- Know about design and simulation of low power techniques using software
- Learn the VLSI design of wireless circuits.

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1. Bosco Leung, “VLSI for Wireless Communication”, Springer, 2011.
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3. www.ccs.neu.edu/home/rraj/Courses/G250/S05/.../SpreadSpectrum.ppt